

Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

SPA555 Series

DESIGNER'S DATA SHEET

Part Number / Ordering Information ¹

SPA555

 $\overline{\mathsf{L}}$ **Screening**²/ __ = Not screened TX = TX Level

TXV = TXV Level S = S Level

^L Terminals^{<u>3</u>/}

= Turret Terminals L = Copper Leads

SM = Surface Mount

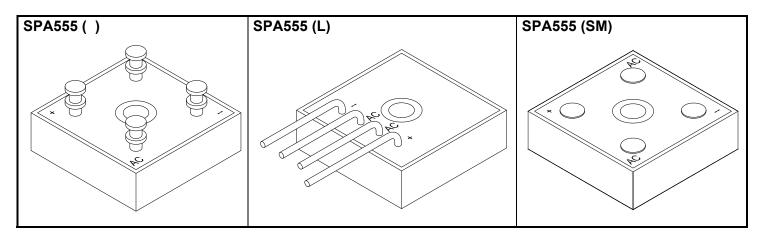
Voltage M = 1000 V N = 1200 V

25 A / 1000 - 1200 V **SIC SCHOTTKY** SINGLE PHASE BRIDGE

Features:

- 1200 V Silicon Carbide Schottky Rectifier
- Average Output Current 25 Amps
- No Reverse Recovery
- **No Forward Recovery**
- No Switching Time Change over Temperature
- Small Package Size (1.25 x 1.25 x 0.350")
- Cases with Aluminum Heatsink are Available. Consult **Factory**
- TX and TXV & S Level Screening Available 2/

Maximum Ratings		Symbol	Value	Units
Peak Repetitive and Peak Surge Reverse Voltage	SPA555M SPA555N	$egin{array}{c} oldsymbol{V_{RSM}} \ oldsymbol{V_{R}} \end{array}$	1000 1200	Volts
Average Rectified Forward Current ^{4/} (Resistive Load, 60 Hz Sine Wave, T _C = 55°C)		Io	25	Amps
Peak Surge Current $\underline{5}^{f}$ (T _A = 25°C, t _P = 10 µs)		I _{FSM}	100	Amps
Operating & Storage Temperature		T _{op} & T _{stg}	-55 to +150	°C
Junction Temperature		TJ	-55 to +200	°C
Maximum Thermal Resistance Junction to Case		R _{eJC}	1.5	°C/W





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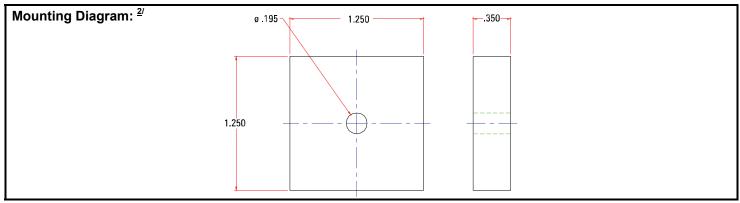
Electrical Characteristic ^{6/}		Symbol	Min	Тур	Max	Units
Instantaneous Forward Voltage Drop (T _A =25°C, 300 - 500 μsec pulse)	I _F = 2.0 A I _F = 5.0 A I _F = 10 A	V _{F1} V _{F2} V _{F3}	_	1.20 1.50 2.10	1.30 1.75 2.50	V _{DC}
Instantaneous Forward Voltage Drop (300 - 500 μsec pulse)	T _A = -55°C, I _F = 5 A T _A = 150 °C, I _F = 5 A	V _{F4} V _{F5}	_	1.35 2.30	1.50 2.80	V _{DC}
Reverse Leakage Current (Rated V _R , T _A = 25°C, 300 μsec pulse minimum)		I _{R1}	_	20	250	μА
Reverse Leakage Current (Rated V _R , T _A = 150°C, 300 μsec pulse minimum)		I _{R2}	_	100	1000	μА
Junction Capacitance (V _R = 10V, f = 1MHz, T _A = 25°C)		CJ	_	280	320	pF

NOTES:

- Pulse Test: Pulse Width = 300 μsec, Duty Cycle = 2%
- 1/ For Ordering Information, Price, and Availability Contact Factory.
- 2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.
- 3/ For Package Outlines Contact Factory.
- $\underline{4}$ / Derate Linearly at 0.28A/°C for T_C > 55°C.
- 5/ Electrical Characteristic per Leg
- 6/ Unless Otherwise Specified, All Electrical Characteristics @25°C.

Available Part Numbers:

SPA555M: SPA555ML: SPA555MSM SPA555N; SPA555NL; SPA555NSM



Terminal Details

